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#### **General Description**

The Himalaya series of voltage regulator ICs, power modules, and chargers enable cooler, smaller, and simpler power supply solutions. The MAX17701 is a high efficiency, high voltage, Himalaya synchronous, step-down, supercapacitor charger controller designed to operate over an input-voltage range of a 4.5V to 60V. The MAX17701 operates over a -40°C to +125°C industrial temperature range and charges a supercapacitor with a ±4% accurate constant current. After the supercapacitor is charged, the device regulates the no-load output voltage with ±1% accuracy. The output voltage is programmable from 1.25V up to (V<sub>DCIN</sub> - 2.1V).

The MAX17701 supercapacitor charger controller is designed to provide a holistic application solution requiring backup energy storage with a precise charging capability. The device uses an external nMOSFET to provide input supply-side short-circuit protection; thus, preventing supercapacitor discharge.

The MAX17701 provides a safety timer (TMR) feature to set the maximum allowed constant current (CC) mode charging time. The device features an uncommitted comparator, which can be used to detect an output overvoltage event (OVI) and prevent the supercapacitor from overcharging. The MAX17701 is available in a 24-pin 4mm x 4mm TQFN package with an exposed pad.

#### **Applications**

- Peak Power Delivery and Energy Storage
- Backup Power for Industrial Safety
- Ride-Through Last-Gasp Supplies
- Portable Medical Equipment
- Building and Home Automation Backup Power

#### SUPERCAPACITOR CHARGING PROFILE WITH 10A LOAD UP TO 60V ₽ VOUT CV MODE CIN V/DIV DCIN GATEN Vin νουτ CC MODE DH FR SUPERCAPACITOR Rs LX SMON VOUT ICHG SYSTEM MAX17701 5A/DIV וח LOAD Vout PGND OVI FLG2 ICHG CSP FLG1 CSN TIME SCALE: 20s/DIV

#### **Simplified Application Circuit**

#### Ordering Information appears at end of data sheet.

#### 19-100772; Rev 6; 6/22

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### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Benefits and Features**

- Optimized Feature Set for Supercapacitor Charging
  - ±4% Charging Current Regulation Accuracy
  - ±6% Charging Current Monitor Accuracy (ISMON)
  - ±1% Voltage Regulation Accuracy
  - Programmable CC Mode Charging Current (ILIM)
  - Wide 4.5V to 60V Input-Voltage Range
  - Adjustable Output-Voltage Range from 1.25V Up To (V<sub>DCIN</sub> - 2.1V)
  - 125kHz to 2.2MHz Adjustable Frequency with External Clock Synchronization (RT/SYNC)
- Reliable Operation in Adverse Environmental Conditions
  - Input Short-Circuit Protection (GATEN)
  - Safety Timer Feature (TMR)
  - Output Overvoltage Protection (OVI)
  - Cycle-by-Cycle Overcurrent Limit
  - Programmable EN/UVLO Threshold
  - Status Output Monitoring Using Open-Drain Outputs (FLG1 and FLG2)
  - Complies with CISPR 32 (EN55032) Class B Conducted and Radiated Emissions
  - Overtemperature Protection
  - Wide -40°C to +125°C Ambient Operating Temperature Range/ -40°C to +150°C Junction Temperature Range

# 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

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### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Absolute Maximum Ratings**

| V <sub>IN</sub> to SGND/EP0.3V to +65V                                  | BST to PGND0.3V to +70V                                 |
|---|---|
| DCIN to SGND/EP0.3V to min(+65V, V <sub>IN</sub> + 0.6V)                | DL to PGND0.3V to (V <sub>CC</sub> + 0.3V)              |
| GATEN to SGND/EP max(-0.3V, DCIN - 0.3V) to (DCIN + 6V)                 | DH to LX0.3V to (BST + 0.3V)                            |
| GATEN to DCIN0.3V to +6V  | EXTVCC to SGND/EP0.3V to +26V                           |
| V <sub>CC</sub> to SGND/EP0.3V to min(+6V, V <sub>IN</sub> + 0.3V)      | PGND, IC1 to SGND/EP0.3V to +0.3V                       |
| CSN, CSP to SGND/EP0.3V to (V <sub>IN</sub> + 0.6V)                     | Continuous Power Dissipation (TA = +70°C) (TQFN (derate |
| CSP to CSN0.3V to +0.3V   | 27.85mW/°C above +70°C))                                |
| V <sub>REF</sub> , TMR, ILIM to SGND/EP0.3V to (V <sub>CC</sub> + 0.3V) | Operating Temperature Range (Note 1)40°C to +125°C      |
| COMP, ISMON, RT/SYNC to SGND/EP0.3V to (V <sub>CC</sub> + 0.3V)         | Junction Temperature+150°C                              |
| OVI, FB to SGND/EP0.3V to +6V   | Storage Temperature Range65°C to +150°C                 |
| FLG1, FLG2, EN/UVLO to SGND/EP0.3V to +6V                               | Lead Temperature (soldering, 10s)+300°C                 |
| LX to PGND0.3V to +65V  | Soldering Temperature (reflow)+260°C                    |
| BST to LX0.3V to +6V  |   |

Note 1: Junction temperature greater than +125°C degrades operating lifetimes.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **Package Information**

#### 24 PIN TQFN

| Package Code                           | T2444+5C         |  |  |  |
|--|------------------|--|--|--|
| Outline Number                         | <u>21-100405</u> |  |  |  |
| Land Pattern Number                    | <u>90-100139</u> |  |  |  |
| Thermal Resistance, Four-Layer Board:  |                  |  |  |  |
| Junction to Ambient (θ <sub>JA</sub> ) | 36°C/W           |  |  |  |
| Junction to Case ( $\theta_{JC}$ )     | 3°C/W            |  |  |  |

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "." in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <u>www.maximintegrated.com/thermal-tutorial</u>.

#### **Electrical Characteristics**

 $(V_{IN} = V_{DCIN} = 24V, C_{VIN} = 4.7\mu\text{F}, C_{DCIN} = 100\text{nF}, C_{VCC} = 4.7\mu\text{F}, C_{VREF} = 100\text{nF}, C_{BST} = 470\text{nF}, V_{EXTVCC} = V_{SGND/EP} = V_{PGND} = V_{FB} = V_{OVI} = V_{IC1} = 0V, V_{EN/UVLO} = V_{LX} = V_{TMR} = V_{ILIM} = V_{CSN} = V_{CSP} = 2.5V, V_{BST} \text{ to } V_{LX} = 5V, \text{RT/SYNC} = \text{DH} = \text{DL} = \text{GATEN} = \text{COMP} = \text{FLG1} = \text{FLG2} = \text{ISMON} = \text{Unconnected}, T_{A} = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. \text{Typical values are at } T_{A} = +25^{\circ}\text{C}.$  All voltages are referenced to SGND/EP, unless otherwise noted.) (Note 2 )

| PARAMETER                     | SYMBOL             | CONDITIONS   | MIN | TYP | MAX | UNITS |
|-------------------------------|--------------------|--|-----|-----|-----|-------|
| POWER SUPPLY                  |                    |  |     |     |     |       |
| DCIN Voltage Range            |                    | DCIN connected to V <sub>IN</sub> , External nMOSFET not used        | 4.5 |     | 60  | V     |
|                               |                    | External nMOSFET used  | 5.5 |     | 60  | 1     |
| V <sub>IN</sub> Voltage Range |                    |  | 4.5 |     | 60  | V     |
| Input Quiescent Current       | I <sub>QNS</sub>   | (V <sub>IN</sub> - V <sub>CSN</sub> ) > 2.1V, V <sub>FB</sub> = 1.5V | 1.4 | 2.1 | 2.8 | mA    |
| Input Switching Current       | I <sub>QS</sub>    |  | 1.7 | 2.5 | 3.5 | mA    |
| Shutdown Supply<br>Current    | I <sub>IN-SH</sub> | V <sub>EN/UVLO</sub> = 0V (Shutdown mode)                            |     | 7   | 18  | μA    |

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Electrical Characteristics (continued)**

 $(V_{IN} = V_{DCIN} = 24V, C_{VIN} = 4.7\mu\text{F}, C_{DCIN} = 100\text{nF}, C_{VCC} = 4.7\mu\text{F}, C_{VREF} = 100\text{nF}, C_{BST} = 470\text{nF}, V_{EXTVCC} = V_{SGND/EP} = V_{PGND} = V_{FB} = V_{OVI} = V_{IC1} = 0V, V_{EN/UVLO} = V_{LX} = V_{TMR} = V_{ILIM} = V_{CSN} = V_{CSP} = 2.5V, V_{BST} \text{ to } V_{LX} = 5V, \text{ RT/SYNC} = DH = DL = GATEN = COMP = FLG1 = FLG2 = ISMON = Unconnected, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at T_A = +25^{\circ}\text{C}. All voltages are referenced to SGND/EP, unless otherwise noted.) (Note 2 )$ 

| PARAMETER                               | SYMBOL               | CONDITIONS  | MIN                      | TYP    | MAX                      | UNITS |
|---|----------------------|---|--------------------------|--------|--------------------------|-------|
| ENABLE/UVLO (EN/UVL                     | O)                   |   |                          |        |                          |       |
| EN/UVLO Rising<br>Threshold             | V <sub>EN_TH_R</sub> | V <sub>EN/UVLO</sub> rising   | 1.22                     | 1.25   | 1.27                     | V     |
| EN/UVLO Falling<br>Threshold            | V <sub>EN_TH_F</sub> |   | 1.07                     | 1.09   | 1.11                     | V     |
| EN/UVLO Bias Current                    | I <sub>EN-BIAS</sub> | V <sub>EN/UVLO</sub> = 0.5V   | 1.4                      | 3.0    | 6.5                      | μA    |
| EN/UVLO True                            | V <sub>ENT</sub>     | V <sub>EN/UVLO</sub> rising   | 0.4                      | 0.7    | 1.1                      | V     |
| Shutdown Threshold                      | ¥EN1                 | Hysteresis  |                          | 60     |                          | mV    |
| V <sub>CC</sub> REGULATORS (INT         | -LDO AND EXT         | -LDO)   |                          |        |                          |       |
|   |                      | 6V < V <sub>IN</sub> < 60V, I <sub>VCC</sub> = 1mA (V <sub>CC</sub><br>supplied from INT-LDO) | 5.00                     | 5.15   | 5.30                     |       |
| V <sub>CC</sub> Output Voltage          | V <sub>CC</sub>      | $V_{IN}$ = 24V, $I_{VCC}$ = 0mA to 75mA, ( $V_{CC}$ supplied from INT-LDO)                    | 4.95                     | 5.10   | 5.25                     | V     |
| VCC Output Voltage                      | VCC                  | $6V < V_{EXTVCC} < 24V$ , $I_{VCC}$ = 1mA (V <sub>CC</sub> supplied from EXT-LDO)             | 5.00                     | 5.15   | 5.30                     |       |
|   |                      | $V_{EXTVCC}$ = 12V, $I_{VCC}$ = 0mA to 75 mA,<br>( $V_{CC}$ supplied from EXT-LDO)            | 4.95                     | 5.10   | 5.25                     |       |
| V <sub>CC</sub> Output Current<br>Limit | IVCC_LIMIT           | $V_{IN}$ = 8.5V, $V_{CC}$ = 4V ( $V_{CC}$ supplied from INT-LDO)                              | 80                       | 110    | 135                      | - mA  |
|   |                      | V <sub>EXTVCC</sub> = 8.5V, V <sub>CC</sub> = 4V (V <sub>CC</sub><br>supplied from EXT-LDO)   | 80                       | 110    | 135                      |       |
|   | V <sub>CC-DO</sub>   | V <sub>IN</sub> = 4.5V, I <sub>VCC</sub> = 75mA (V <sub>CC</sub> supplied from IN-LDO)        |                          | 370    | 750                      |       |
| V <sub>CC</sub> Dropout Voltage         |                      | V <sub>EXTVCC</sub> = 4.9V, I <sub>VCC</sub> = 75mA (V <sub>CC</sub> supplied from EXT-LDO)   |                          | 185    | 350                      | mV    |
| V <sub>CC</sub> Undervoltage            | V <sub>CC-UVR</sub>  | V <sub>CC</sub> rising  | 4.14                     | 4.20   | 4.26                     |       |
| Threshold                               | V <sub>CC-UVF</sub>  | V <sub>CC</sub> falling   | 3.74                     | 3.80   | 3.86                     | V     |
| EXTVCC Voltage Range                    |                      |   | 4.8                      |        | 24.0                     | V     |
| EXTVCC Switchover                       |                      | V <sub>EXTVCC</sub> rising  | 4.63                     | 4.70   | 4.77                     | v     |
| Voltage                                 |                      | Hysteresis  |                          | 0.24   |                          | v     |
| OSCILLATOR (RT/SYNC                     | )                    |   |                          |        |                          |       |
|   |                      | R <sub>RT/SYNC</sub> = 350 kΩ   | 118.75                   | 125.00 | 131.25                   |       |
| Switching Frequency                     | form                 | R <sub>RT/SYNC</sub> = Unconnected  | 332.5                    | 350.0  | 367.5                    | kHz   |
| ownering r requercy                     | fsw                  | $R_{\rm RT/SYNC}$ = 110k $\Omega$   | 380                      | 400    | 420                      | KI IZ |
|   |                      | R <sub>RT/SYNC</sub> = 19kΩ   | 2090                     | 2200   | 2310                     | 1     |
| Synchronization<br>Frequency Range      | <sup>f</sup> SYNC    |   | 0.9 x<br>f <sub>SW</sub> |        | 1.1 x<br>f <sub>SW</sub> | kHz   |
| External Clock<br>Amplitude             |                      | C <sub>COUPLING</sub> = 10pF  | 3                        |        |                          | V     |
| SYNC High Pulse-Width                   |                      |   | 100                      |        |                          | ns    |
| SYNC Low Pulse-Width                    |                      |   | 100                      |        |                          | ns    |

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Electrical Characteristics (continued)**

 $(V_{IN} = V_{DCIN} = 24V, C_{VIN} = 4.7\mu\text{F}, C_{DCIN} = 100\text{nF}, C_{VCC} = 4.7\mu\text{F}, C_{VREF} = 100\text{nF}, C_{BST} = 470\text{nF}, V_{EXTVCC} = V_{SGND/EP} = V_{PGND} = V_{FB} = V_{OVI} = V_{IC1} = 0V, V_{EN/UVLO} = V_{LX} = V_{TMR} = V_{ILIM} = V_{CSN} = V_{CSP} = 2.5V, V_{BST} \text{ to } V_{LX} = 5V, \text{ RT/SYNC} = DH = DL = GATEN = COMP = FLG1 = FLG2 = ISMON = Unconnected, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at T_A = +25^{\circ}\text{C}.$ All voltages are referenced to SGND/EP, unless otherwise noted.) (Note 2)

| PARAMETER                               | SYMBOL                 | CONDITIONS   | MIN   | TYP   | MAX                   | UNITS |  |
|---|------------------------|--|-------|-------|-----------------------|-------|--|
| SYNC Input-Leakage<br>Current           | ISYNC_LKG              | V <sub>RT/SYNC</sub> = 2.5V, T <sub>A</sub> = +25°C              | -100  |       | +100                  | nA    |  |
| GATE DRIVER                             |                        | •  |       |       |                       |       |  |
| DH to BST On-<br>Resistance             |                        | Source 100mA   | 0.8   | 1.2   | 2.1                   | Ω     |  |
| DH to LX On-Resistance                  |                        | Sink 100mA   | 0.3   | 0.6   | 1.0                   | Ω     |  |
| DL to V <sub>CC</sub> On-<br>Resistance |                        | Source 100mA   | 0.8   | 1.2   | 2.1                   | Ω     |  |
| DL to PGND On-<br>Resistance            |                        | Sink 100mA   | 0.3   | 0.6   | 1.0                   | Ω     |  |
| DH Minimum Controlled<br>On Time        | <sup>t</sup> MIN_ON_DH |  | 60    | 80    | 100                   | ns    |  |
| DL Minimum<br>Guaranteed On Time        | <sup>t</sup> MIN_ON_DL |  | 60    | 80    | 100                   | ns    |  |
| Dead Time                               | <sup>t</sup> DT_HL     | DH falling to DL rising, $C_{DH-LX} = 6nF$ , $C_{DL-PGND} = 6nF$ |       | 30    |                       | ns    |  |
|   | <sup>t</sup> DT_LH     | DL falling to DH rising, $C_{DH-LX} = 6nF$ , $C_{DL-PGND} = 6nF$ |       | 30    |                       |       |  |
| DH Transition Time                      | t <sub>HR</sub>        | DH rising, C <sub>DH-LX</sub> = 6nF                              |       | 25    |                       | ~~~   |  |
|   | t <sub>HF</sub>        | DH falling, C <sub>DH-LX</sub> = 6nF                             |       | 11    |                       | ns    |  |
| DL Transition Time                      | t <sub>LR</sub>        | DL rising, C <sub>DL-PGND</sub> = 6nF                            |       | 25    |                       | 20    |  |
|   | tLF                    | DL falling, C <sub>DL-PGND</sub> = 6nF                           |       | 11    |                       | ns    |  |
| REFERENCE VOLTAGE                       | (VREF)                 |  |       |       |                       |       |  |
| V <sub>REF</sub> Output Voltage         | V <sub>REF</sub>       | I <sub>VREF</sub> = 0 to 1mA                                     | 2.465 | 2.500 | 2.535                 | V     |  |
| Reference Current Limit                 | I <sub>REF_LIM</sub>   | V <sub>REF</sub> = 2.45V   | 1.2   | 1.8   | 2.7                   | mA    |  |
| CURRENT SENSE (CSP,                     | CSN, ILIM)             |  |       |       |                       |       |  |
| CSP, CSN Common<br>Mode Voltage Range   |                        |  | 0     |       | (V <sub>IN</sub> - 2) | V     |  |
| CSP to CSN Input<br>Operating Voltage   | V <sub>DIFF_CS</sub>   | $V_{DIFF_{CS}} = (V_{CSP} - V_{CSN})$                            | -10   |       | +100                  | mV    |  |
|   |                        | V <sub>ILIM</sub> = 1.5V   | 48    | 50    | 52                    |       |  |
| CSP to CSN Regulation                   |                        | V <sub>ILIM</sub> = 0.75V  | 23    | 25    | 27                    | mV    |  |
| Voltage Accuracy                        | V <sub>CSREG</sub>     | V <sub>ILIM</sub> = 0.15V  | 3     | 5     | 7                     |       |  |
|   |                        | V <sub>ILIM</sub> = V <sub>REF</sub>                             | 48    | 50    | 52                    |       |  |
| CSP Pin Current                         |                        | CSP source   |       | 200   | 1400                  | nA    |  |

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Electrical Characteristics (continued)**

 $(V_{IN} = V_{DCIN} = 24V, C_{VIN} = 4.7\mu\text{F}, C_{DCIN} = 100\text{nF}, C_{VCC} = 4.7\mu\text{F}, C_{VREF} = 100\text{nF}, C_{BST} = 470\text{nF}, V_{EXTVCC} = V_{SGND/EP} = V_{PGND} = V_{FB} = V_{OVI} = V_{IC1} = 0V, V_{EN/UVLO} = V_{LX} = V_{TMR} = V_{ILIM} = V_{CSN} = V_{CSP} = 2.5V, V_{BST} \text{ to } V_{LX} = 5V, \text{ RT/SYNC} = DH = DL = GATEN = COMP = FLG1 = FLG2 = ISMON = Unconnected, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at T_A = +25^{\circ}\text{C}.$ All voltages are referenced to SGND/EP, unless otherwise noted.) (Note 2)

| PARAMETER   | SYMBOL                                       | COND  | MIN   | TYP   | MAX   | UNITS |       |
|---|--|---|---|-------|-------|-------|-------|
|   |  | V <sub>EN/UVLO</sub> = 0V, CS                                   | N sink  |       | 1.3   | 2.3   |       |
| CSN Pin Current                                       |  | Charger on, V <sub>ILIM</sub><br>= 0.15V to 1.5V                | I <sub>CHG</sub> ><br>I <sub>CHGMAX</sub> /10, CSN<br>source          | 250   | 400   | 550   | μA    |
|   |  | (see Note 3)  | I <sub>CHG</sub> <<br>I <sub>CHGMAX</sub> /10, CSN<br>sink            | 470   | 700   | 1000  |       |
| Current Loop Error<br>Amplifier<br>Transconductance   | 9mi  | $(V_{CSP} - V_{CSN}) = V_C$                                     | SNEG ±25mV  | 275   | 480   | 685   | μS    |
| ILIM Input-Leakage<br>Current                         |  | V <sub>ILIM</sub> = 1.5V, T <sub>A</sub> = +                    | 25°C  | -100  |       | +100  | nA    |
| CSN Undervoltage-                                     | Maaaaaaa                                     | (V <sub>IN</sub> - V <sub>CSN</sub> ), rising                   |   | 1.97  | 2.04  | 2.10  | v     |
| Lockout Threshold                                     | VCMUVLO                                      | (V <sub>IN</sub> - V <sub>CSN</sub> ), falling                  |   | 1.88  | 1.95  | 2.02  |       |
| Overcurrent Threshold                                 | Veenserv                                     | V <sub>CSPEAK</sub> = (V <sub>CSP</sub> -                       | V <sub>CSN</sub> ), V <sub>ILIM</sub> = 1.5V                          | 70    | 75    | 80    | - mV  |
|   | V <sub>CSPEAK</sub>                          | Hysteresis  |   |       | 10    |       |       |
| Zero Cross Threshold                                  | V <sub>ZX</sub>                              | (V <sub>CSP</sub> - V <sub>CSN</sub> ) falling                  | g   | 3     | 4.5   | 6     | mV    |
| PWM Ramp Amplitude                                    | V <sub>RAMP</sub>                            | f <sub>SW</sub> = 125kHz to 2.2                                 | MHz   | 1.37  | 1.44  | 1.51  | V     |
| VOLTAGE REGULATION                                    | I AMPLIFIER (F                               | В)  |   |       |       |       |       |
| FB Reference Voltage                                  | V <sub>FB_REG</sub>                          |   |   | 1.237 | 1.250 | 1.263 | V     |
| FB Input-Leakage<br>Current                           |  | V <sub>FB</sub> = 1.3V, T <sub>A</sub> = +2                     | 5°C   | -100  |       | +100  | nA    |
| Voltage Loop Error<br>Amplifier Gain                  | G <sub>V</sub>                               |   |   | 1.15  | 1.30  | 1.42  | mV/mV |
| INPUT SHORT-CIRCUIT                                   | PROTECTION (                                 | GATEN)  |   |       |       |       |       |
| External nMOSFET<br>Gate Drive Voltage                | (V <sub>GATEN</sub> -<br>V <sub>DCIN</sub> ) |   |   | 4.65  | 5.0   | 5.5   | V     |
| GATEN Drive Current                                   | IGATEN                                       |   |   | 17    | 20    | 23    | μA    |
| GATEN Active Pulldown<br>Resistance                   | R <sub>GATEN_</sub> A                        | I <sub>GATEN</sub> = 100mA                                      |   |       | 1.1   | 2.1   | Ω     |
| GATEN Passive<br>Pulldown Resistance                  | R <sub>GATEN_P</sub>                         | V <sub>EN/UVLO</sub> = 0V                                       |   |       | 400   | 800   | Ω     |
| GATEN-DCIN Threshold                                  | V <sub>GATEN_</sub> OK                       |   |   | 3.20  | 3.55  | 3.90  | V     |
| GATEN OK Delay  | tGATEN_OK                                    |   |   |       | 15    |       | ms    |
| External nMOSFET                                      |  | (V <sub>DCIN</sub> - V <sub>IN</sub> ) falling                  |   | -111  | -93   | -75   |       |
| Reverse-Blocking<br>Threshold                         | V <sub>REV</sub>                             | Hysteresis  |   |       | 20    |       | mV    |
| External nMOSFET<br>Reverse-Blocking<br>Response Time |  | C <sub>GATEN-DCIN</sub> = 10n<br>93mV) to (V <sub>GATEN</sub> - | F, V <sub>DCIN</sub> < (V <sub>IN</sub> -<br>V <sub>DCIN</sub> ) < 2V |       | 100   | 180   | ns    |
| VIN to DCIN Reverse                                   |  | V <sub>DCIN</sub> = 0V, V <sub>IN</sub> =                       | V <sub>EN/UVLO</sub> = 0V   |       | 170   | 260   |       |
| Leakage Current                                       |  | 60V   |   |       | 230   | 350   | μA    |

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Electrical Characteristics (continued)**

 $(V_{IN} = V_{DCIN} = 24V, C_{VIN} = 4.7\mu\text{F}, C_{DCIN} = 100\text{nF}, C_{VCC} = 4.7\mu\text{F}, C_{VREF} = 100\text{nF}, C_{BST} = 470\text{nF}, V_{EXTVCC} = V_{SGND/EP} = V_{PGND} = V_{FB} = V_{OVI} = V_{IC1} = 0V, V_{EN/UVLO} = V_{LX} = V_{TMR} = V_{ILIM} = V_{CSN} = V_{CSP} = 2.5V, V_{BST} \text{ to } V_{LX} = 5V, \text{ RT/SYNC} = DH = DL = GATEN = COMP = FLG1 = FLG2 = ISMON = Unconnected, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at T_A = +25^{\circ}\text{C}.$ All voltages are referenced to SGND/EP, unless otherwise noted.) (Note 2)

| PARAMETER                               | SYMBOL                 | CONDITIONS   | MIN   | TYP    | MAX   | UNITS         |  |
|---|------------------------|--|-------|--------|-------|---------------|--|
| CHARGER FUNCTIONS                       |                        | · · · · · ·  |       |        |       |               |  |
| Constant Voltage (CV)                   |                        | V <sub>ILIM</sub> = 1.5V, V <sub>FB</sub> rising                     | 97.15 | 97.50  | 97.85 | % of          |  |
| Mode FB Threshold                       | V <sub>FB_CV</sub>     | Hysteresis   |       | 0.3    |       | $V_{FB\_REG}$ |  |
| Overvoltage Comparator                  |                        | V <sub>OVI</sub> rising  | 1.245 | 1.260  | 1.275 | v             |  |
| Threshold (OVI)                         | V <sub>OVI_TH</sub>    | V <sub>OVI</sub> falling   | 1.235 | 1.250  | 1.265 | v             |  |
| ISMON Output-Voltage                    |                        | (V <sub>CSP</sub> - V <sub>CSN</sub> ) = 50mV                        | 1.41  | 1.50   | 1.59  | v             |  |
| Accuracy                                |                        | $(V_{CSP} - V_{CSN}) = 10 mV$  | 0.21  | 0.30   | 0.39  | •             |  |
| ISMON Output<br>Resistance              |                        |  |       | 90     |       | kΩ            |  |
| ISMON Output<br>Bandwidth               |                        |  |       | 100    |       | kHz           |  |
| CHARGER TIMER (TMR)                     |                        |  |       |        |       |               |  |
| Charger Startup Delay                   | tou or or              | C <sub>TMR</sub> = 33nF, TMR enabled                                 |       | 27     |       | me            |  |
|   | <sup>t</sup> CH_START  | TMR disabled   |       | 26     |       | – ms          |  |
| TMR Oscillator Upper<br>Threshold       | V <sub>TMR_H</sub>     |  | 1.47  | 1.50   | 1.53  | V             |  |
| TMR Oscillator Lower<br>Threshold       | V <sub>TMR_L</sub>     |  | 0.94  | 0.96   | 0.98  | V             |  |
| TMR Source/Sink<br>Current              | I <sub>TMR</sub>       |  | 8.9   | 10     | 10.9  | μA            |  |
| TMR Disable Threshold                   | V <sub>TMR_DIS</sub>   | V <sub>TMR</sub> > V <sub>TMR_DIS</sub> (powerup check only)         | 1.9   | 2.0    | 2.1   | V             |  |
| TMR Short to SGND/EP<br>Fault Threshold | V <sub>TMR_GND</sub>   | V <sub>TMR</sub> < V <sub>TMR_GND</sub> (powerup check only)         | 80    | 100    | 120   | mV            |  |
| Constant Current (CC)<br>Mode Timeout   | <sup>t</sup> FCHG      |  |       | 32767  |       | TMR<br>CYCLES |  |
| TMR Fault Blanking<br>Timeout           | <sup>t</sup> BLANK_OFF |  |       | 131071 |       | TMR<br>CYCLES |  |
| CHARGER STATUS OUT                      | PUTS (FLG1, F          | LG2)   |       |        |       | ·             |  |
| FLG1/FLG2 Pulldown<br>Voltage           |                        | I <sub>FLG1</sub> , I <sub>FLG2</sub> = 10mA                         |       |        | 500   | mV            |  |
| FLG1/FLG2 Leakage<br>Current            |                        | V <sub>FLG1</sub> , V <sub>FLG2</sub> = 5.5V, T <sub>A</sub> = +25°C | -100  |        | +100  | nA            |  |
| IC THERMAL PROTECTI                     | ON                     | · ·  |       |        |       |               |  |
| Thermal Shutdown                        |                        | Temperature rising   |       | 160    |       | - °C          |  |
| Threshold                               |                        | Hysteresis   |       | 10     |       |               |  |

Note 2: Electrical specifications are production tested at T<sub>A</sub> = +25°C. Specifications over the entire operating temperature range are guaranteed by design and characterization.

Note 3: CC mode charging current setting is calculated using this equation:

$$I_{\text{CHGMAX}} = \frac{V_{\text{CSREG}}}{R_{\text{S}}}$$

where  $R_S$  is the current sense resistor.

## 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Typical Operating Characteristics**

 $(V_{DCIN} = 24V, V_{SGND/EP} = V_{PGND} = 0V, RT/SYNC = unconnected (f_{SW} = 350kHz), T_A = +25^{\circ}C$ , unless otherwise noted. All voltages are referenced to SGND/EP, unless otherwise noted.)



### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Typical Operating Characteristics (continued)**

 $(V_{DCIN} = 24V, V_{SGND/EP} = V_{PGND} = 0V, RT/SYNC = unconnected (f_{SW} = 350kHz), T_A = +25^{\circ}C$ , unless otherwise noted. All voltages are referenced to SGND/EP, unless otherwise noted.)







CONDITIONS: 2.5V OUTPUT, CV MODE,  $I_{LOAD}$  = 10A













CONDITIONS: 5V OUTPUT, CV MODE,  $I_{LOAD}$  = 10A





### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Typical Operating Characteristics (continued)**

 $(V_{DCIN} = 24V, V_{SGND/EP} = V_{PGND} = 0V, RT/SYNC = unconnected (f_{SW} = 350kHz), T_A = +25^{\circ}C$ , unless otherwise noted. All voltages are referenced to SGND/EP, unless otherwise noted.)



#### **Pin Configuration**

#### MAX17701



# 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

### **Pin Description**

| PIN  | NAME             | FUNCTION   |
|------|------------------|--|
| 1    | PGND             | Power Ground. Connect to the return terminal of a $V_{CC}$ bypass capacitor placed close to IC, and the source terminal of external low-side nMOSFET. Refer to the MAX17701 EV kit data sheet for a PCB layout example.  |
| 2    | V <sub>CC</sub>  | Internal LDO Output. Connect a minimum of 4.7 $\mu$ F/0805, low-ESR ceramic capacitor between V <sub>CC</sub> and PGND. V <sub>CC</sub> supports the IC internal control circuitry and gate drive current for external nMOSFETs.   |
| 3    | EXTVCC           | External Power-Supply Input for EXT-LDO. To power internal circuitry from an external supply, apply a voltage between 4.8V and 24V to the EXTVCC pin. Connect a minimum of $1\mu$ F/0603, low-ESR ceramic capacitor between EXTVCC and SGND/EP. Leave EXTVCC open when not used.   |
| 4    | CSP              | Inverting Input of the Current Loop Error Amplifier. The CSP and CSN pins measure the voltage across the current sense resistor $R_S$ (see Figure 4).  |
| 5    | CSN              | Non-Inverting Input of the Current Loop Error Amplifier. Connect CSN to the node connecting the output capacitor and current sense resistor $R_S$ . Use Kelvin connections and route the CSP and CSN traces as a differential pair (see Figure 4).   |
| 6    | ISMON            | Output of Charging Current Monitor. Bypass ISMON with a 1nF low-ESR ceramic capacitor to SGND/EP. The voltage on this pin is 30 times the voltage drop across the current sense resistor $R_{S}$ .   |
| 7, 8 | FLG2, FLG1       | Open-Drain Status Output Pins. Connect a $10k\Omega$ pullup resistor each from V <sub>CC</sub> to the FLG1 and FLG2 pins. See the <u>Charger Status Outputs (FLG1, FLG2)</u> section for more details.   |
| 9    | FB               | Feedback Input. Connect FB to the center node of a resistor-divider from the positive terminal of supercapacitor to SGND/EP to set the output voltage. See the <u>Setting the Output Voltage and</u> <u>Voltage Regulation Loop (FB)</u> section for more details.   |
| 10   | COMP             | Current Loop Error Amplifier Output. Connect a compensation network at this pin to stabilize the inner current loop. See the <u>Current Regulation Loop Compensation (COMP)</u> section for more details.  |
| 11   | TMR              | Supercapacitor Safety Timer Setting Pin. A capacitor from TMR to SGND/EP sets the charging time in CC mode. Place the timer capacitor close to the TMR pin. Connect TMR to $V_{REF}$ to disable the timer function. See the <u>Charger Timers (TMR)</u> section for more details.  |
| 12   | RT/SYNC          | Switching Frequency Programming/Synchronization Input. Connect a resistor from RT/SYNC to SGND/EP to set the switching frequency between 125kHz to 2.2MHz. Leave RT/SYNC open for the default 350kHz frequency. See the <u>Setting the Switching Frequency and External Clock</u> <u>Synchronization (RT/SYNC)</u> section for more details. |
| 13   | ILIM             | CC Mode Charging Current Programming Input. Connect ILIM to the center node of a resistor divider between V <sub>REF</sub> and SGND/EP to set the CC mode charging current. Connect to V <sub>REF</sub> for default CC mode charging current setting. See the <u>CC Mode Charging Current Setting (ILIM)</u> section for more details.       |
| 14   | V <sub>REF</sub> | 2.5V Reference Output. Bypass $V_{REF}$ with a 0.1µF low-ESR ceramic capacitor to SGND/EP. See the <u>Reference Voltage (V<sub>REF</sub>)</u> section for more details.  |
| 15   | OVI              | Overvoltage Detection Input. Connect OVI to the center node of a resistor divider from the output voltage node to SGND/EP. If $V_{OVI}$ exceeds $V_{OVI\_TH}$ , charging is stopped and the charger enters into the latched fault.   |
| 16   | IC1              | Internal Connection. Connect to SGND/EP  |
| 17   | EN/UVLO          | Enable/Undervoltage Lockout Input. Connect to the center node of a resistor divider between DCIN and SGND/EP to set the input voltage at which the device turns on. Connect to SGND/EP to shutdown the device. See the <u>Setting the Input Undervoltage-Lockout Level (EN/UVLO)</u> section for more details.                               |

# 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

## **Pin Description (continued)**

| PIN    | NAME            | FUNCTION  |
|--------|-----------------|---|
| 18     | DCIN            | Input Supply Voltage Sense Pin. Bypass DCIN with a 0.1 $\mu$ F ceramic capacitor to PGND. The DCIN and V <sub>IN</sub> pins measure the voltage across external nMOSFET. Use Kelvin connections and route the V <sub>IN</sub> and DCIN traces as differential pair. Refer to the MAX17701 EV kit data sheet for the recommended PCB layout and routing. If input short-circuit protection feature is not used, connect DCIN to V <sub>IN</sub> close to IC. |
| 19     | GATEN           | Gate Drive Output for External nMOSFET. Bypass GATEN with a 2.2nF low-ESR ceramic capacitor to DCIN. GATEN controls the gate of an external nMOSFET connected between DCIN and $V_{IN}$ to prevent supercapacitor discharge when DCIN is shorted to PGND. See the <u>Input Short</u> <u>Circuit Protection (GATEN)</u> section for more details.  |
| 20     | V <sub>IN</sub> | MAX17701 IC Supply Pin. Bypass V <sub>IN</sub> to PGND with a 0.1 $\mu$ F ceramic capacitor. Refer to the MAX17701 EV kit data sheet for the recommended PCB layout and routing.  |
| 21     | DH              | High Side nMOSFET Gate Driver Output. Connect to the gate of a high-side nMOSFET.   |
| 22     | LX              | Switching Node Connection Input. Connect to the switching node of the converter.  |
| 23 BST |                 | Bootstrap Capacitor Connection Input. Connect a $0.1\mu$ F (min) capacitor between the BST and LX pins. Connect a Schottky diode from V <sub>CC</sub> to the BST pin. See the <u>Bootstrap Capacitor Selection</u> and <u>Bootstrap Diode Selection</u> sections for more details.  |
| 24     | DL              | Low-Side nMOSFET Gate Driver Output. Connect to the gate of a low-side nMOSFET.   |
| _      | SGND/EP         | Signal Ground, Exposed Pad. Refer to the MAX17701 EV kit data sheet recommended method for the PCB layout, routing, and thermal vias.   |

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Functional Diagrams**

#### MAX17701 Block Diagram



### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Detailed Description**

The MAX17701 is a 4.5V to 60V, synchronous, step-down, supercapacitor charger controller designed to operate over a -40°C to +125°C temperature range. It charges a supercapacitor with constant charging current with up to  $\pm$ 4% accuracy. After the supercapacitor is charged, the device regulates the no load output voltage with  $\pm$ 1% accuracy. The MAX17701 supports a wide output-voltage range of 1.25V to (V<sub>DCIN</sub> - 2.1V).

The MAX17701 features a constant frequency, average current-mode control architecture shown in Figure 1. An internal current loop consists of a transconductance amplifier  $g_{mi}$  that senses the inductor current flowing through current sense resistor  $R_S$  as a voltage drop across the CSP and CSN pins. The current sense voltage is compared with a current loop reference voltage ( $V_{REFI}$ ), which is set by the outer voltage loop error amplifier ( $G_V$ ) and limited by the voltage programmed at the ILIM pin ( $V_{ILIM}$ ). The voltage at the COMP pin is compared with a 1.44V (typ) ramp using a PWM comparator to set the duty cycle of the converter. The required compensation to stabilize the current loop is applied at the COMP pin using  $R_Z$ ,  $C_Z$ , and  $C_P$ . Under steady-state conditions, the inner current loop forces the voltage drop across  $R_S$  equal to  $V_{REFI}$ .

The output voltage is monitored by the voltage error amplifier  $G_V$  with a resistor divider ( $R_{TOP}$ ,  $R_{BOT}$ ) connected across the positive and negative supercapacitor terminals with the center node connected to the FB pin. The voltage at the FB pin ( $V_{FB}$ ) is compared with the FB reference voltage ( $V_{FB}$  REG). The voltage loop error amplifier sets the current loop

reference voltage (V<sub>REFI</sub>). V<sub>REFI</sub> is limited to  $\frac{V_{\text{ILIM}}}{30}$  until  $V_{\text{FB}} \leq \left[V_{\text{FB}_{\text{REG}}} - \frac{V_{\text{ILIM}}}{30 \times G_V}\right]$ . This results in a constant current

through R<sub>S</sub>. When the output voltage rises, such that  $V_{FB} > \left[V_{FB\_REG} - \frac{V_{ILIM}}{30 \times G_V}\right]$ ,  $V_{REFI}$ ; hence, the output load current

 $(I_{LOAD})$  proportionately reduces. The steady-state FB regulation voltage, and consequently the output voltage depend on the load  $(I_{LOAD})$  connected across the supercapacitor, as given by the following equation:

$$V_{\text{OUT\_LOAD}} = \left[ V_{\text{FB\_REG}} - \frac{I_{\text{LOAD}} \times R_{S}}{G_{V}} \right] \times \left[ \frac{R_{\text{TOP}} + R_{\text{BOT}}}{R_{\text{BOT}}} \right]$$

where,

V<sub>FB REG</sub> = FB reference voltage

VOUT LOAD = Steady-state output voltage for a given load current

ILOAD = Output load current of the charger

R<sub>TOP</sub>, R<sub>BOT</sub> = Output voltage feedback voltage divider resistors

G<sub>V</sub> = Voltage loop error amplifier gain (1.30mV/mV)

The MAX17701 provides input short-circuit protection, and prevents supercapacitor discharging for input supply-side short-circuit events by means of an external nMOSFET. A safety timer (TMR) sets the maximum allowed CC mode charging time to improve system safety. The device features an uncommitted comparator, which can be used to detect an output overvoltage (OVI), which improves the safety of load circuitry, and prevents the supercapacitor from overcharging.

The switching frequency of the device can be programmed from 125kHz to 2.2 MHz using a resistor at the RT/SYNC pin. The RT/SYNC also provides an external clock synchronization feature. Input undervoltage lockout is implemented using the EN/UVLO pin. Two open-drain status outputs (FLG1 and FLG2) indicate the supercapacitor charger status. The system current can be monitored using the ISMON pin.

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller



Figure 1. Average Current Mode Control Loop

#### **Power-Up/-Down Sequence**

<u>Figure 2</u> shows the MAX17701 power-up/-down sequence when DCIN voltage is applied/removed. When DCIN voltage reaches a level such that  $V_{EN/UVLO}$  is around 0.7V ( $V_{ENT}$ ) the INT-LDO regulator is enabled and  $V_{CC}$  rises. When  $V_{CC}$  rises above 4.2V ( $V_{CC-UVR}$ ) and  $V_{EN/UVLO}$  rises above 1.25V ( $V_{EN_TH_R}$ ), the MAX17701 initiates EN/UVLO debounce and checks for hardware faults. If there are no hardware faults (see the <u>Hardware Faults</u> section) detected at power-up, the MAX17701 enables internal blocks during charger startup delay time t<sub>CH\_START</sub>. After this delay, the charger initiates LX switching and enters CC mode. In CC mode, the current is regulated at the CC mode charging current setting (I<sub>CHGMAX</sub>). The safety timer counts the charging time in CC mode and if the output voltage reaches constant voltage mode ( $V_{FB} > V_{FB_CV}$ ) within the safety timer setting (t<sub>SC\_TMR</sub>), the charger enters constant voltage (CV) mode and continues to operate.

When  $V_{EN/UVLO}$  falls below 1.09V ( $V_{EN_TH_F}$ ), the MAX17701 initiates a shutdown sequence with a debounce time of 2ms (typ). If the input voltage decreases such that ( $V_{IN} - V_{CSN}$ ) falls below the current loop error amplifier undervoltage lockout falling threshold 1.95V ( $V_{CMUVLO}$ ), the MAX17701 initiates a shutdown sequence immediately. The converter stops switching, and GATEN is pulled down with 1.1 $\Omega$  ( $R_{GATEN_A}$ ) to DCIN to turn off the external nMOSFET. The COMP is pulled low after a debounce time of 100µs (typ).

If  $V_{EN/UVLO}$  falls below 0.64V ( $V_{ENT}$ ), the MAX17701 initiates a shutdown sequence with a debounce time of 10µs (typ). During this shutdown sequence, the MAX17701 pulls down the GATEN with 1.1 $\Omega$  ( $R_{GATEN_A}$ ) to DCIN to turn off the external nMOSFET. See the <u>Setting the Input Undervoltage-Lockout Level (EN/UVLO</u>) section for more details.

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller



Figure 2. Charger Power-Up/-Down Sequence

#### Input Short-Circuit Protection (GATEN)

The MAX17701 provides gate drive output (GATEN) that drives a logic-level gate threshold external nMOSFET, which turns off and prevents supercapacitor discharging for input supply short-circuit events. The GATEN is pulled up with  $20\mu A (I_{GATEN})$  when  $V_{IN}$  is 2.04V ( $V_{CMUVLO}$ ) above  $V_{CSN}$ . If  $V_{GATEN}$  does not reach 3.55V ( $V_{GATEN_OK}$ ) within 15ms ( $t_{GATEN_OK}$ ), MAX17701 enters latched hardware fault.

Figure 3 depicts the MAX17701 behavior when DCIN is shorted to PGND. When V<sub>DCIN</sub> is 93mV (V<sub>REV</sub>) below V<sub>IN</sub>,

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

GATEN is pulled down with 1.1 $\Omega$  (R<sub>GATEN\_A</sub>) and the external nMOSFET is turned off within 100ns (typ). When V<sub>EN/</sub> UVLO goes below 0.64V (V<sub>ENT</sub>), the MAX17701 shuts down with 10µs (typ) debounce time. When DCIN-to-PGND short is removed, the power-up sequence is initiated (see the <u>Power-Up/Down Sequence</u> section).

Measure the differential voltage between the source and drain terminals of the input short-circuit protection external nMOSFET using a Kelvin connection. Shield DCIN, V<sub>IN</sub> and GATEN signal traces using static ground plane on either side of the traces and on the adjacent layers of PCB. Place the  $0.1\mu$ F decoupling capacitors on DCIN and V<sub>IN</sub> pins close to MAX17701. The MAX17701 EV kit depicts the recommended layout and routing of DCIN, V<sub>IN</sub> and GATEN traces.

When the input short-circuit protection is not used, connect a 2.2nF capacitor between GATEN and DCIN, and short DCIN to  $V_{IN}$ .



Figure 3. Input Short-Circuit Protection and Recovery Timing Diagram

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### **Charger Operation**

MAX17701 offers constant current (CC) mode and constant voltage (CV) mode for charging a supercapacitor. In CC mode, the charging current is regulated to the CC mode charging current ( $I_{CHGMAX}$ ) proportional to  $V_{ILIM}$ . The safety timer starts counting when the device enters CC mode. When  $V_{FB}$  goes above 1.219V ( $V_{FB}_{CV}$ ) within the CC mode timeout period ( $t_{SC}_{TMR}$ ), the charger enters CV mode and the safety timer stops counting (see <u>Charger Timers (TMR</u>) section). The safety timer count resets when the device enters CV mode. In CV mode, the device continues to charge the supercapacitor until  $V_{FB}$  reaches 1.250V ( $V_{FB}_{REG}$ ). The charger regulates  $V_{FB}$  at  $V_{FB}_{REG}$  at no load. When  $V_{FB}$  drops below 1.215V ( $V_{FB}_{CV}$ ), the charger exits CV mode, enters CC mode, and the timer count restarts.

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### Charger Timers (TMR)

The MAX17701 offers a programmable timer feature to provide additional safety to the supercapacitor and the connected load. Connect a capacitor from TMR to SGND/EP to enable the timer feature. Connect TMR to V<sub>REF</sub> to disable the timer feature. The timer counts the charging time in CC mode. If V<sub>FB</sub> does not reach 1.219V (V<sub>FB</sub> <sub>CV</sub>) within CC mode timeout period ( $t_{SC}$  <sub>TMR</sub>), the charger turns off. The charger restarts after 4 times  $t_{SC}$  <sub>TMR</sub>. The MAX17701 supports 470pF to 10µF capacitance on TMR, translating into a CC mode timeout period range of 1.5 second to 9 hours.

The safety timer is programmed based on maximum supercapacitor value ( $C_{SUP}$ ), output voltage ( $V_{OUT}$ ), and CC mode charging current setting ( $I_{CHGMAX}$ ). Refer to the <u>CC Mode Charging Current Setting (ILIM</u>) section.

Choose the required safety timer period using the following equation:

$$t_{\text{SC}_{\text{TMR}}} \ge \frac{c_{\text{SUP}} \times v_{\text{OUT}}}{I_{\text{CHGMAX}} - I_{\text{LOAD}}}$$

where I<sub>LOAD</sub> is the system load during the supercapacitor charging period

Select  $I_{CHGMAX} \ge 1.5 \times I_{LOAD}$  to ensure the charger enters CV mode

Use the following equation to calculate  $C_{TMR}$  for the required  $t_{SC}$  TMR:

$$C_{\text{TMR}} \ge 1.15 \times \left(\frac{{}^{t}_{\text{SC}\_\text{TMR}}}{2 \times {}^{t}_{\text{FCHG}}} - 1.2 \times 10^{-6}\right) \times \left(\frac{{}^{t}_{\text{TMR}}}{{}^{V}_{\text{TMR}\_\text{H}} - {}^{V}_{\text{TMR}\_\text{L}}}\right)$$

where

t<sub>SC TMR</sub> = Desired safety timer timeout setting in seconds

C<sub>TMR</sub> = TMR capacitor in Farad

t<sub>FCHG</sub> = Number of TMR cycles in CC mode (32767)

 $V_{\text{TMR} \text{ H}}$  = TMR oscillator upper threshold (1.5V)

 $V_{TMR L}$  = TMR oscillator lower threshold (0.96V)

I<sub>TMR</sub> = TMR pin source/sink current (10µA)

#### Charger Status Outputs (FLG1, FLG2)

The MAX17701 features two open-drain status output pins (FLG1 and FLG2) to indicate the status of the charger. Table 1 shows the status flag summary.

#### Table 1. Status Output Indications

| CHARGER STATUS FLG (FLG2<br>and FLG1) | FLG2                               | FLG1                               | CHARGER STATUS                            |  |
|---------------------------------------|------------------------------------|------------------------------------|---|--|
| 11                                    | Open drain in Hi-<br>Impedance (1) | Open drain in Hi-<br>Impedance (1) | Charger Off                               |  |
| 10                                    | Open drain in Hi-<br>Impedance (1) | Open drain pulls low (0)           | CC Mode                                   |  |
| 00                                    | Open drain pulls low (0)           | Open drain pulls low (0)           | CV Mode                                   |  |
| 01                                    | Open drain pulls low (0)           | Open drain in Hi-<br>Impedance (1) | Hardware Fault or Safety Timer<br>Timeout |  |

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

#### Hardware Faults

The MAX17701 features hardware fault checks at power-up and during normal operation. <u>Table 2</u> provides various fault detection features available and their behaviors in MAX17701.

#### Table 2. Protection Under System Faults

| FAULT CONDITION   | FAULT MONITOR STATE                 | FAULT BEHAVIOR   |  |
|---|-------------------------------------|--|--|
| RT/SYNC to SGND/EP short  |                                     |  |  |
| GATEN to DCIN short   |                                     |  |  |
| TMR pin left unconnected  |                                     |  |  |
| TMR to SGND/EP short  | Power-up check                      |  |  |
| V <sub>REF</sub> to SGND/EP short                                     |                                     |  |  |
| Output overvoltage (V <sub>OVI</sub> ><br>V <sub>OVI_TH</sub> )       |                                     | Latched fault, need to recycle power or EN/UVLO to restart<br>the device |  |
| (V <sub>GATEN</sub> - V <sub>DCIN</sub> ) <<br>V <sub>GATEN_</sub> OK |                                     |  |  |
| $V_{REF}$ < 1.95V or $V_{REF}$ > 3.05V                                | Continuous, during normal operation |  |  |
| Output overvoltage (V <sub>OVI</sub> ><br>V <sub>OVI_TH</sub> )       |                                     |  |  |

#### Linear Regulator (V<sub>CC</sub> and EXTVCC)

The MAX17701 integrates two internal low-dropout (LDO) linear regulators INT-LDO and EXT-LDO that power V<sub>CC</sub>. V<sub>CC</sub> powers gate drivers and internal control circuitry. INT-LDO is powered from V<sub>IN</sub> and turns on when V<sub>EN/UVLO</sub> > V<sub>ENT</sub> (0.7V). EXT-LDO is powered from EXTVCC. At any time, only one of these two linear regulators operates, depending on the EXTVCC voltage. If V<sub>EXTVCC</sub> > 4.7V (typ) then V<sub>CC</sub> is powered from EXT-LDO. If V<sub>EXTVCC</sub> < 4.46V(typ), then V<sub>CC</sub> is powered from INT-LDO. Powering V<sub>CC</sub> from EXTVCC reduces on-chip dissipation and increases efficiency at higher input voltages. Connect EXTVCC to V<sub>OUT</sub> for applications with V<sub>OUT</sub> ≥ 4.8V. The maximum voltage limit on EXTVCC is 24V. Bypass EXTVCC with a 1µF ceramic capacitor to SGND/EP. Leave EXTVCC open when not used. Bypass V<sub>CC</sub> to PGND with at least a 4.7µF/0805, low-ESR ceramic capacitor.

#### Reference Voltage (V<sub>REF</sub>)

The MAX17701 provides a 2.5V reference voltage on the V<sub>REF</sub> pin with ±1.4% accuracy. V<sub>REF</sub> can be used to program V<sub>ILIM</sub> to set the CC mode charging current (I<sub>CHGMAX</sub>). Connect a minimum 0.1µF low-ESR ceramic capacitor between V<sub>REF</sub> and SGND/EP. See the <u>CC Mode Charging Current Setting (ILIM</u>) section for more details.

#### Setting the Switching Frequency and External Clock Synchronization (RT/SYNC)

The switching frequency of the device can be programmed from 125kHz to 2.2MHz by using a resistor ( $R_{RT/SYNC}$ ) connected from the RT/SYNC pin to SGND/EP.  $R_{RT/SYNC}$  can be calculated using the following equation:

$$R_{\text{RT/SYNC}} = \frac{44830}{f_{\text{SW}}} - 1.205$$

Where  $R_{RT/SYNC}$  is in k $\Omega$  and  $f_{SW}$  is in kHz. Leave the RT/SYNC pin unconnected to operate the device at 350kHz default switching frequency.

The MAX17701 can be synchronized to an external clock coupled to the RT/SYNC pin through a 10pF ceramic capacitor. The external clock is detected after checking the rising edge for 112 cycles of the internal clock (set by RT/SYNC). If the external clock frequency is within the allowed SYNC frequency range ( $\pm$ 10% of nominal internal clock frequency), the device stops switching for 2 switching time periods and then restarts with an external clock. When the external clock is removed, the device stops switching for 10 switching time periods and then restarts with an internal clock.

The minimum external clock pulse-width should be greater than 100ns. The off-time duration of the external clock should be at least 100ns.

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#### Peak Current-Limit

The MAX17701 provides a cycle-by-cycle overcurrent protection by limiting the peak current-sense voltage ( $V_{CSP}$  -  $V_{CSN}$ ) across the current sense pins. When an overcurrent event (( $V_{CSP}$  -  $V_{CSN}$ ) >  $V_{CSPEAK}$ ) is detected, the overcurrent comparator in the MAX17701 terminates the DH pulse and limits the peak current. The overcurrent fault is not latched.

#### **Charging Current Monitoring (ISMON)**

The output charge current can be monitored by observing the voltage at the ISMON pin. Connect a 1nF ceramic capacitor on ISMON to filter out the switching frequency component in the ISMON voltage. The charging current is given by the following equation:

$$I_{\rm CHG} = \frac{V_{\rm ISMON}}{30 \times R_{\rm S}}$$

where,  $I_{CHG}$  = Charging current  $V_{ISMON}$  = Voltage at the ISMON pin  $R_S$  = Current-sense resistance

#### **Thermal-Shutdown Protection**

Thermal-shutdown protection limits junction temperature of the device. When the junction temperature of the device exceeds +160°C, an on-chip thermal sensor shuts down the device, allowing the device to cool. The device turns on after the junction temperature reduces by 10°C. Carefully evaluate the total power dissipation to avoid unwanted triggering of the thermal shutdown during normal operation (see the <u>Device Power Dissipation</u> section).

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#### **Applications Information**

#### **Inductor Selection**

Three key inductor parameters must be specified for operation with the device: inductance value (L), DC resistance ( $R_{DCR}$ ), and inductor saturation current ( $I_{SAT}$ ).

The required inductance is calculated based on the inductor current ripple ratio (LIR), i.e., ratio of peak-to-peak ripple current ( $\Delta I_L$ ) to CC mode charging current (ICHGMAX). A good compromise between size and loss is an LIR of 0.3.

The inductance value (L) is given by the higher value of the two calculated inductances:

$$L1 = \frac{V_{OUT} \times (1-D)}{LIR \times I_{CHGMAX} \times f_{SW}}$$
$$L2 = \frac{V_{OUT}}{1-1}$$

600000 × ICHGMAX

where:

V<sub>OUT</sub> = Desired voltage across supercapacitor

I<sub>CHGMAX</sub> = CC mode charging current

D = Duty cycle of the converter,  $V_{OUT}/V_{IN}$ 

VIN = Nominal input voltage

f<sub>SW</sub> = Switching frequency in Hz

Select an inductor that is nearest to the calculated value. The inductor RMS-current rating should be more than the CC mode charging current. Select a low-loss inductor with acceptable dimensions and the lowest possible DC resistance. The saturation current rating ( $I_{SAT}$ ) of the inductor must be high enough to ensure that saturation can occur only above the overcurrent threshold corresponding to  $V_{CSPEAK}$ .

#### **Output Capacitor Selection**

Supercapacitors have significant equivalent series resistance (ESR<sub>SUP</sub>). The switching ripple component of charger output current flows into this ESR<sub>SUP</sub> and results in a large output-voltage ripple. To reduce the voltage ripple across the supercapacitor, additional X7R ceramic capacitors and/or low-ESR POSCAP capacitors can be used at the output of the charger.

X7R ceramic output capacitors are preferred due to their stability over temperature in industrial applications. For higher values of output capacitance, low-ESR POSCAP capacitors can be used in parallel with ceramic capacitors.

Calculate the required output capacitance (C<sub>OUT</sub>) based on the following equation:

$$C_{OUT} = \frac{\frac{25 \times I_{CHGMAX}}{f_{SW} \times V_{OUT}}$$

where:

I<sub>CHGMAX</sub> = CC mode charging current setting

f<sub>SW</sub> = Switching frequency in Hz

V<sub>OUT</sub> = Desired voltage across the supercapacitor

Derating of ceramic capacitors with DC-bias voltage must be considered while selecting the capacitors, using the manufacturer data sheet. The selected output capacitor  $C_{OUT\_SEL}$  and its equivalent series resistance (ESR<sub>COUT</sub>) affect the output-voltage ripple ( $\Delta V_{OUT}$ ). Estimate the resultant  $\Delta V_{OUT}$  using the following equation:

$$\Delta V_{OUT} \approx \Delta I_L \times \left( \mathsf{ESR}_{\mathsf{COUT}} + \frac{1}{8 \times f_{\mathsf{SW}} \times C_{\mathsf{OUT}}} \right)$$

where  $\Delta I_L$  is the inductor peak-to-peak ripple current.

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In applications with a long cable between the charger output and the supercapacitor, to dampen the oscillations caused by the interaction of the cable inductance with the low ESR output capacitors of the charger circuit, an electrolytic capacitor with appropriate ESR (equivalent series resistance) may be used. Choose an electrolytic capacitor equal to 1.5 times the value of C<sub>OUT\_SEL</sub>. Select an electrolytic capacitor with an equivalent series resistance (ESR<sub>ELCO</sub>) as calculated below:

$$\mathsf{ESR}_{\mathsf{ELCO}} = \sqrt{\frac{L_{\mathsf{CABLE}}}{C_{\mathsf{OUT}}\mathsf{SEL}}}$$

where L<sub>CABLE</sub> is the output cable inductance.

#### **Input Capacitor Selection**

The input filter capacitor reduces peak currents drawn from the power source and reduces noise and voltage ripple on the input caused by the switching converter. Calculate the required input capacitance at  $V_{IN}$  ( $C_{VIN}$ ) using the following equation:

$$C_{\text{VIN}} = \frac{I_{\text{CHGMAX}} \times D \times (1 - D)}{\eta \times f_{\text{SW}} \times \Delta V_{\text{IN}}}$$

where:

D =  $\frac{V_{OUT}}{V_{IN}}$  is the duty ratio of the converter

 $f_{SW}$  = Switching frequency in Hz

 $\Delta V_{IN}$  = Allowable input-voltage ripple

 $\eta$  = Efficiency of the converter

I<sub>CHGMAX</sub> = CC mode charging current

Choose  $\Delta V_{IN} \le 0.5V$  to minimize voltage ripple across the external nMOSFET and to provide robust operation during input short-circuit events.

The input capacitor RMS current ( $I_{RMS}$ ) is calculated using the following equation:

 $I_{\text{RMS}} = I_{\text{CHGMAX}} \times \frac{\sqrt{V_{\text{OUT}} \times [V_{\text{IN}} - V_{\text{OUT}}]}}{V_{\text{IN}}}$ 

Choose low-ESR ceramic input capacitors that exhibit less than a  $+10^{\circ}$ C temperature rise at I<sub>RMS</sub> for optimal long-term reliability. X7R capacitors are recommended in industrial applications for their temperature stability. Derating of ceramic capacitors with DC-bias voltage must be considered while selecting the capacitors using the manufacturer data sheet.

Choose an electrolytic capacitor at DCIN in order to prevent the DCIN voltage from being less than -0.3V during input short events. An electrolytic capacitor also provides the damping for potential oscillations caused by inductance of the longer input power path and input ceramic capacitor ( $C_{VIN}$ ). Additionally, if required, add a Schottky diode at DCIN in parallel with the electrolytic capacitor.

#### **Operating Input-Voltage Range**

The following equations are used to calculate the operating input-voltage range for a given output voltage and CC mode charging current setting. The minimum operating input voltage on the DCIN pin is given by the higher value from the two calculated voltages:

$$V_{\text{DCIN}(\text{MIN1})} = \left( \frac{V_{\text{OUT}} + I_{\text{CHGMAX}} \times \left( R_{\text{DS}}_{\text{ON}(\text{LS})} + R_{\text{DCR}(\text{MAX})} \right)}{\left( 1 - \left( 1.05 \times f_{\text{SW}} \times \left( t_{\text{DT}}_{\text{HL}} + t_{\text{MIN}}_{\text{ON}}_{\text{DL}(\text{MAX})} \right) \right) \right)} + I_{\text{CHGMAX}} \times \left( R_{\text{DS}}_{\text{ON}(\text{HS})} - R_{\text{DS}}_{\text{ON}(\text{LS})} \right) \right)$$

$$V_{\text{DCIN}(\text{MIN2})} = V_{\text{OUT}} + 2.1V$$

where:

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 $V_{DCIN(MIN1)}$ ,  $V_{DCIN(MIN2)}$  = Minimum operating input voltages; the higher of the two values is the minimum operating input voltage ( $V_{DCIN(MIN)}$ )

 $V_{OUT}$  = Desired regulation voltage across the supercapacitor

I<sub>CHGMAX</sub> = CC mode charging current setting

 $f_{SW}$  = Switching frequency in Hz

 $R_{DCR(MAX)}$  = Worst-case DC resistance of the inductor in  $\Omega$ 

 $R_{DS_ON(HS)}$ ,  $R_{DS_ON(LS)}$  = Maximum on-state resistances of high-side and low-side MOSFETs in  $\Omega$ , respectively  $t_{DT_HL}$  = Dead time (30ns)

t<sub>MIN ON DL(MAX)</sub> = Worst-case DL minimum controlled on-time (100ns).

The maximum operating input voltage on the DCIN pin is calculated as follows:

 $V_{\text{DCIN(MAX)}} = \frac{V_{\text{OUT}}}{\left(1.05 \times f_{\text{SW}} \times t_{\text{MIN}_{\text{ON}_{\text{DH}}}(\text{MAX})}\right)}$ 

where  $t_{MIN_ON_DH(MAX)}$  is the worst-case DH minimum controlled on-time (100ns).

#### CC Mode Charging Current Setting (ILIM)

The CC mode charge current setting involves setting up a voltage on the ILIM pin (V<sub>ILIM</sub>) and choice of current sense resistor R<sub>S</sub>. Selection of R<sub>S</sub> involves a trade-off between power loss and charging current accuracy. The best MAX17701 charging current accuracy is obtained with a voltage drop (V<sub>CSP</sub> - V<sub>CSN</sub>) of 50mV across R<sub>S</sub>. (V<sub>CSP</sub> - V<sub>CSN</sub>) can be reduced at the expense of the charging current accuracy to reduce power loss. The recommended range for voltage across R<sub>S</sub> is 25mV (±8% charging current accuracy) to 50mV (±4% charging current accuracy). R<sub>S</sub> can be calculated using the following equation:

$$R_{\rm S} = \frac{\left(V_{\rm CSP} - V_{\rm CSN}\right)}{I_{\rm CHGMAX}}$$

Once  $R_S$  is selected,  $V_{ILIM}$  can be calculated using the following equation:

#### $V_{\rm ILIM} = 30 \times R_{\rm S} \times I_{\rm CHGMAX}$

A resistor divider from  $V_{REF}$  to SGND/EP can be used to program  $V_{ILIM}$ , as shown in Figure 4. The resistor-divider values are calculated as follows:

$$R_{\text{LIM1}} = 20 \times (V_{\text{REF}} - V_{\text{ILIM}}) k\Omega$$

$$R_{\text{LIM2}} = 20 \times V_{\text{ILIM}} k\Omega$$

The permitted voltage range for the V<sub>ILIM</sub> setting is 0.15V to 1.5V. The MAX17701 can be set to the default I<sub>CHGMAX</sub> setting corresponding to (V<sub>CSP</sub> - V<sub>CSN</sub>) = 50mV across R<sub>S</sub> by connecting ILIM to V<sub>REF</sub>.

Connect an R-C filter in the current-sense signal path as shown in Figure 4 to attenuate switching noise while preserving accuracy and bandwidth. The R-C filter corner frequency should be 5 times the switching frequency. The recommended filter resistance (R1) is  $40\Omega$  for minimal impact on the current-sense accuracy. The filter should be placed close to the CSP and CSN pins. Calculate the value of filter capacitor C1 using the following equation:

$$C1 = \frac{1}{2\pi x R 1 x 5 x f_{SW}}$$

where  $f_{SW}$  = Switching frequency in Hz

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Figure 4. Current-Sense Circuit

#### Setting the Input Undervoltage-Lockout Level (EN/UVLO)

The MAX17701 offers an adjustable input undervoltage-lockout level using the EN/UVLO pin. Pulling the EN/UVLO pin below 1.09V (typ) stops charger operation. Pulling EN/UVLO below 0.64V (typ) causes the MAX17701 to shut down. In this state, the device draws  $I_{IN-SH}$  (7µA) quiescent current. Figure 5 shows the recommended EN/UVLO configuration based on the required input-voltage range.

Connect EN/UVLO to the center node of a resistor divider from the DCIN to SGND/EP to set the input voltage at which the device turns on. Choose R1 as follows:

 $R1 \leq (10000 \times V_{\text{DCIN(MIN)}})$ 

where  $V_{DCIN(MIN)}$  is the voltage at which the device is required to turn on.

Calculate the value of R2 using the following equation:

$$R2 = \frac{V_{\text{EN}_{\text{TH}_{\text{R}}} \times R1}}{(V_{\text{DCIN(MIN)}} - V_{\text{EN}_{\text{TH}_{\text{R}}} R} + (I_{\text{EN}_{\text{-}} \text{BIAS}} \times R1))}$$

where:

 $I_{EN-BIAS}$  = Internal bias pullup current on the EN/ULVO pin (3µA)

 $V_{EN_TH_R}$  = EN/UVLO rising threshold voltage (1.25V)



Figure 5. Setting Input-Undervoltage Lockout

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#### **Current Regulation Loop Compensation (COMP)**

The MAX17701 features a COMP pin to tune the current loop control performance of the average current mode controller. Refer to Figure 1 for a depiction of the compensation network on the COMP pin using R<sub>Z</sub>, C<sub>Z</sub>, and C<sub>P</sub>. The choice of the compensation component values depends on the chosen inductor (L) and its DC resistance (R<sub>DCR</sub>), switching frequency (f<sub>SW</sub>), current-sense resistor (R<sub>S</sub>), maximum operating input voltage (V<sub>DCIN(MAX)</sub>), the desired regulation voltage across supercapacitor (V<sub>OUT</sub>), the worst-case maximum ESR of the supercapacitor (ESR<sub>SUP</sub>), the maximum on-resistances of the step-down converter nMOSFETs (R<sub>DS\_ON(HS)</sub> and R<sub>DS\_ON(LS)</sub>) and the maximum cabling and contact resistances (R<sub>CONNECTION</sub>) in the charging path.

Calculate the compensation resistor R<sub>Z</sub> using the following equation:

$$R_Z = \frac{3000 \times L \times f_{SW}}{V_{DCIN(MAX)} \times R_S}$$

Calculate the compensation capacitor C<sub>7</sub> using the following equation:

$$C_Z = \frac{0.8 \times L}{R_Z \times R_E}$$

where

$$R_{E} = \left[ R_{\text{DCR}} + R_{S} + R_{\text{DS}}_{\text{ON(HS)}} \times D_{\text{MIN}} + R_{\text{DS}}_{\text{ON(LS)}} \times (1 - D_{\text{MIN}}) + \text{ESR}_{\text{SUP}} + R_{\text{CONNECTION}} \right]$$
$$D_{\text{MIN}} = \frac{V_{\text{OUT}}}{V_{\text{DCIN(MAX)}}}$$

Calculate the high frequency pole capacitor C<sub>P</sub> using the following equation:

$$C_{\mathsf{P}} = \frac{0.35}{R_Z \times f_{\mathsf{SW}}}$$

#### Setting the Output Voltage and Voltage Regulation Loop (FB)

The MAX17701 features a FB pin to regulate the voltage across the supercapacitor to a desired level. Connect a feedback resistor divider ( $R_{TOP}$  and  $R_{BOT}$ ) with a compensating capacitor ( $C_{FB}$ ), as depicted in <u>Figure 1</u>. The choice of feedback components depends on the desired regulation voltage across the supercapacitor ( $V_{OUT}$ ), the chosen switching frequency ( $f_{SW}$ ), and the operating input-voltage range ( $V_{DCIN(MAX)}$  and  $V_{DCIN(MIN)}$ ).

Calculate  $\mathsf{R}_{TOP}$  and  $\mathsf{R}_{BOT}$  using the following equations:

$$R_{\text{TOP}} = 10 \times V_{\text{OUT}} \quad k\Omega$$
$$R_{\text{BOT}} = \frac{R_{\text{TOP}}}{\left(\frac{V_{\text{OUT}}}{V_{\text{FB}}\text{_REG}} \cdot 1\right)} \quad k\Omega$$

where  $\mathsf{V}_{\mathsf{FB}\_\mathsf{REG}}$  is the FB reference voltage.

Calculate C<sub>FB</sub> using the following equation:

$$C_{\text{FB}} = \frac{1}{1.5 \times 10^6 \times R_{\text{PAR}}}$$

where

 $R_{\rm PAR} = \frac{R_{\rm TOP} \times R_{\rm BOT}}{R_{\rm TOP} + R_{\rm BOT}} \text{ in } k\Omega.$ 

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#### **Output Overvoltage Protection (OVI)**

The MAX17701 provides an overvoltage detection comparator at the OVI pin. The overvoltage level for the supercapacitor can be set by connecting OVI to the midpoint of a resistor-divider from output to SGND/EP as shown in Figure 6.

Select R1 in the range of  $50k\Omega$  to  $100k\Omega$ .

Calculate resistor R2 from the following equation:

$$R2 = \frac{R1}{\left(\frac{V_{OUT} OV}{V_{OVI} TH} - 1\right)}$$

where

V<sub>OUT OV</sub> = Overvoltage level of the supercapacitor

 $V_{OVI}$  TH = Overvoltage comparator threshold (1.26V)



Figure 6. Setting the Supercapacitor Overvoltage Level

#### **Bootstrap Capacitor Selection**

Bootstrap capacitance ( $C_{BST}$ ) value is determined by the selection of the high-side nMOSFET(s). Choose  $C_{BST}$  using the following equation:

$$C_{BST} \ge \frac{\Delta Q_G}{\Delta V_{BST}}$$

where:

 $\Delta Q_G$  = Total gate charge of the high-side nMOSFET(s)

 $\Delta V_{BST}$  = Voltage variation allowed on the high-side nMOSFET(s) driver after turn-on

Choose  $\Delta V_{BST} \le 100 \text{mV}$  to select C<sub>BST</sub>. The bootstrap capacitor should be a low-ESR ceramic capacitor. A minimum value of  $0.1 \mu$ F is recommended.

#### **Bootstrap Diode Selection**

Select a Schottky diode with the following ratings:

- Reverse voltage rating ≥ (Maximum input operating voltage + 10V)
- Average forward current rating ≥ 1A

Choose a diode with low forward-voltage drop and low reverse-leakage current across the operating temperature range.

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#### Input Short-Circuit Protection External nMOSFET Selection

The MAX17701 is designed to control an external logic level nMOSFET that turns Off in less than 100ns and isolates the V<sub>IN</sub> node from input short-circuit events. This feature prevents discharge of the supercapacitor into the input during input (DCIN) short-circuit events. The external nMOSFET used for this feature only turns On once during power-up and turns Off during shutdown; therefore, the nMOSFET does not need to be optimized for switching performance. This external nMOSFET should therefore be selected with low  $R_{DS-ON}$  for low forward path conduction losses. The MAX17701 supports external nMOSFETs with gate charge up to 250nC at  $V_{GS}$  = 3.9V. Using larger values results in a gate charging time larger than 15ms (t<sub>GATEN OK</sub>) and causes the MAX17701 to enter a latched Fault condition.

#### Step-Down Converter nMOSFET Selection

The MAX17701 drives two external logic-level nMOSFETs to implement the step-down converter high-side and low-side switches. These nMOSFETs must be logic-level compatible with guaranteed on-resistance specifications provided at  $V_{GS}$  = 4.5V. The key selection parameters to choose these MOSFETs include:

- On-resistance (R<sub>DS-ON</sub>)
- Maximum drain-to-source voltage (V<sub>DS(MAX)</sub>)
- Miller Plateau voltage on the nMOSFET Gaté (V<sub>MIL</sub>)
- Total gate charge (Q<sub>G</sub>)
- Output capacitance (C<sub>OSS</sub>)
- Power-dissipation rating and package thermal resistance
- Maximum operating junction temperature

For the step-down converter, nMOSFETs should be chosen in such a way that the switching losses and conduction losses are balanced and optimized. The duty cycles for the high-side and low-side external nMOSFETs can be calculated as follows:

$$D = \frac{V_{OUT}}{V_{IN}}$$

High-side nMOSFET duty cycle: D

Low-side nMOSFET duty cycle: 1 - D

High-side nMOSFET losses can be estimated using the following formula:

PHS-MOSFET = PHS-MOSFET\_CONDUCTION + PHS-MOSFET\_SWITCHING

 $P_{HS-MOSFET_CONDUCTION} = I_{CHG}^2 \times R_{DS-ON(HS)} \times D$ 

 $\mathsf{P}_{\mathsf{HS}-\mathsf{MOSFET}_{\mathsf{SWITCHING}}} = f_{\mathsf{SW}} \times \left( \left[ \frac{V_{\mathsf{IN}} \times I_{\mathsf{CHG}}}{2} \times \frac{Q_{\mathsf{SW}} \times R_{\mathsf{DR}}}{V_{\mathsf{CC}} - V_{\mathsf{MIL}}} \right] + \left[ V_{\mathsf{IN}} \times Q_{\mathsf{rr}} \right] + \left[ \frac{1}{2} \times C_{\mathsf{OSSHS}} \times V_{\mathsf{IN}}^2 \right] + \left[ \frac{1}{2} \times C_{\mathsf{OSSLS}} \times V_{\mathsf{IN}}^2 \right] \right)$ 

where:

f<sub>SW</sub> = Switching frequency in Hz

I<sub>CHG</sub> = Charging current

Q<sub>SW</sub> = Switching charge of the high-side nMOSFET from the nMOSFET data sheet,

R<sub>DR</sub> = Sum of the DH pin driver pullup resistance and the high-side nMOSFET internal gate resistance,

 $V_{MIL}$  =  $V_{GS}$  of the high-side nMOSFET that corresponds to  $I_D$  =  $I_{CHGMAX}$  on the  $V_{GS}$  vs.  $I_D$  curve in the nMOSFET data sheet

Q<sub>rr</sub> = Reverse-recovery charge of low-side nMOSFET(s) body diode

 $C_{OSSHS}$  = Effective output capacitance of the high-side nMOSFET(s)  $C_{OSSLS}$  = Effective output capacitance of the low-side nMOSFET(s)

Low-side nMOSFET losses can be estimated using the following formula:

$$P_{\text{LS}-\text{MOSFET}} = \left( I_{\text{CHG}}^2 \times R_{\text{DS}-\text{ON}(\text{LS})} \times (1-D) + V_D \times I_{\text{CHG}} \times t_{\text{DT}} \times f_{\text{SW}} \times 2 \right)$$

where:

 $V_D$  = Forward-drop of the low-side nMOSFET(s) body diode

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 $t_{DT}$  = Dead time (30ns)

Take R<sub>DS-ON</sub> variation with respect to temperature into account while calculating the power losses and ensure that the losses of each nMOSFET do not exceed their power rating and operate within a safe junction temperature rating. When parallel nMOSFETs are used, it is recommended to use appropriate independent series gate resistors for each nMOSFET to account for gate charge variation from one nMOSFET to another.

#### **Device Power Dissipation**

The MAX17701 must dissipate losses due to quiescent current consumption and the internal gate driver.

If  $V_{CC}$  is powered from  $V_{IN}$ , use the following equation to calculate the approximate IC losses:

$$P_{MAX17701} = V_{IN} \times \left[ \left[ Q_G \times f_{SW} \right] + I_{QNS} \right]$$

When  $V_{OUT}$  is used to power  $V_{CC}$  by connecting the EXTVCC pin to an output voltage greater than 4.8V, use the following equation to calculate the approximate IC losses:

 $P_{MAX17701} = V_{EXTVCC} \times \left[ \left[ Q_G \times f_{SW} \right] + I_{QNS} \right]$ 

where:

Q<sub>G</sub> = Total gate charge of high-side and low-side nMOSFETs,

IQNS = Input Quiescent current (2.1mA)

 $f_{SW}$  = Switching frequency in Hz

Calculate the junction temperature using the following equation and ensure that it does not exceed +125°C.

$$T_J = T_{A(MAX)} + (\theta_{JA} \times P_{MAX17701})$$

where:

 $T_J$  = Junction temperature

 $P_{MAX17701}$  = Power loss in the device

 $\theta_{JA}$  = Junction-to-ambient thermal resistance

T<sub>A(MAX)</sub> = Maximum ambient temperature

#### **PCB Layout Guidelines**

Careful PCB layout is critical to achieve low losses and low EMI emissions. Use the following guidelines for PCB layout:

- Place ceramic input filter capacitors as close as possible across the drain of the high-side nMOSFET and source of the low-side nMOSFET.
- Use Kelvin connections and route the V<sub>IN</sub> and DCIN traces from input short-circuit protection nMOSFET source and drain terminals as a differential pair and connect to V<sub>IN</sub> and DCIN pins of the device. Place V<sub>IN</sub> and DCIN bypass capacitors close to V<sub>IN</sub> and DCIN pins, respectively.
- Place V<sub>CC</sub> and EXTVCC bypass capacitors and the BST capacitor near the respective pins.
- Place GATEN-to-DCIN bypass capacitor close to the GATEN, DCIN pins of the device.
- Place the bootstrap capacitor close to the BST and LX pins of the device.
- Route the bootstrap diode connections from the V<sub>CC</sub> capacitor and to the bootstrap capacitor as short as possible to minimize the loop inductance.
- Route switching traces (BST, LX, DH, and DL) away from sensitive signal traces (RT/SYNC, COMP, CSP, CSN and FB).
- The gate current traces must be short in length. Use multiple vias to route these signals if routed from one layer of the PCB to another layer.
- Route current-sense traces as a differential pair to minimize the loop inductance and avoid differential noise.
- Place a current-sense filter resistor and capacitor near the CSP and CSN pins.
- Place feedback and compensation components close to the device and connect to the SGND/EP copper area.
- Place all power components on the top side of the board and run the power-stage currents using traces or copper fills on the top side only without adding vias wherever possible.

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- Keep the power traces and load connections short. Use multilayer, thick copper PCBs (2oz or higher) to enhance efficiency and minimize trace inductance and resistance.
- Allocate a large PGND copper area for the output node and connect the return terminals of the input filter capacitors, output capacitors, and the source terminals of the low-side nMOSFET(s) to that area.
- Refer to the MAX17701 EV kit data sheet for recommended PCB layout and routing.

#### **Typical Application Circuit**

#### 20A Supercapacitor Charger



Figure 7. 5V/20A Supercapacitor Charger

## 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller



#### **Typical Application Circuit (continued)**

Figure 8. 2.5V/20A Supercapacitor Charger

# 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

## **Ordering Information**

|               | PART NUMBER  | TEMPERATURE RANGE | PIN-PACKAGE |  |
|---------------|--------------|-------------------|-------------|--|
|               | MAX17701ATG+ | -40°C to +125°C   | 24 TQFN-EP  |  |
| MAX17701ATG+T |              | -40°C to +125°C   | 24 TQFN-EP  |  |

+ Denotes a lead(Pb)-free/RoHS-compliant package.

T Denotes tape-and-reel.

### 4.5V to 60V, Synchronous Step-Down Supercapacitor Charger Controller

## **Revision History**

| REVISION<br>NUMBER | REVISION<br>DATE | DESCRIPTION   | PAGES<br>CHANGED                            |
|--------------------|------------------|---|---|
| 0                  | 4/20             | Initial release   |   |
| 1                  | 6/20             | Updated the General Description, Benefit and Features, Simplified Application<br>Circuit, Absolute Maximum Ratings, Electrical Characteristics, Detailed Description,<br>Operating Input-Voltage Range, CC Mode Charging Current Settings (ILIM), Step-<br>Down Converter nMOSFET Selection, and Typical Application Circuit (Figures 7 and<br>8) sections  | 1–2, 6, 13,<br>21–23,<br>27, 29–30          |
| 2                  | 11/20            | Updated the Pin Description, Charger Timers, PCB Layout Guidelines and Typical Application Circuit (Figures 7 and 8) sections, and Table 1; replaced TOC01 with new TOC01a and TOC01b in the Typical Operating Characteristics section  | 8, 11, 17–18,<br>27–29                      |
| 3                  | 3/21             | Updated the General Description, Benefits and Features, Simplified Application<br>Circuit, Absolute Maximum Ratings, Electrical Characteristics, Pin Configuration, Pin<br>Description, MAX17701 Block Diagram, Detailed Description, Power-Up/-Down<br>Sequence, Input Short-Circuit Protection (GATEN), Charger Operation, Charger<br>Timers (TMR), Hardware Faults, Linear Regulator (V <sub>CC</sub> and EXTVCC), Peak<br>Current-Limit, Inductor Selection, Operating Input-Voltage Range, CC Mode<br>Charging Current Setting (ILIM), PCB Layout Guidelines, and the Typical Application<br>Circuit sections; updated TOC14 in Typical Operating Characteristics section; added<br>the Charger Status Outputs (FLG1, FLG2) and Bootstrap Diode Selection sections | 1–2, 4–6, 9,<br>11–24, 26–27,<br>29–31      |
| 4                  | 12/21            | Updated Electrical Characteristics, Pin Description, Detailed Description, Typical<br>Operating Characteristics TOC1a, TOC1b, TOC2, TOC5, TOC7, TOC12, TOC17,<br>Input Short-Circuit Protection (GATEN), Inductor Selection, Output Capacitor<br>Selection, Input Capacitor Selection, Operating Input-Voltage Range, CC Mode<br>Charging Current Setting (ILIM), Setting the Input Undervoltage-Lockout Level (EN/<br>UVLO), Current Regulation Loop Compensation (COMP), Setting the Output Voltage<br>and Voltage Regulation Loop (FB), Input Short-Circuit Protection External nMOSFET<br>Selection, Device Power Dissipation, PCB Layout Guidelines, and Typical<br>Application Circuit, 20A Supercapacitor Charger sections                                       | 5, 8, 9, 12, 17<br>21–25, 27, 28,<br>30, 31 |
| 5                  | 02/22            | Updated MAX17701 Block Diagram  | 12  |
| 6                  | 6/22             | Updated <i>Benefits and Features</i> section, added TOC19 and TOC20 in <i>Typical Operating Characteristics</i> section   | 1, 9  |



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